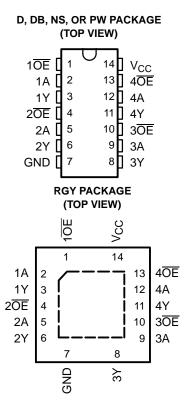


FEATURES

- Operates From 1.65 V to 3.6 V
- Specified From –40°C to 85°C and –40°C to 125°C
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4.8 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2 V at V_{CC} = 3.3 V, T_A = 25°C
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



DESCRIPTION/ORDERING INFORMATION

This quadruple bus buffer gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74LVC125A features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable (\overline{OE}) input is high.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

ORDERING INFORMATION

T _A	PACKA	GE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
–40°C to 85°C	QFN – RGY	Reel of 1000	SN74LVC125ARGYR	LC125A	
		Tube of 50	SN74LVC125AD		
	SOIC - D	Reel of 2500	SN74LVC125ADR	LVC125A	
		Reel of 250	SN74LVC125ADT		
–40°C to 125°C	SOP - NS	Reel of 2000	SN74LVC125ANSR	LVC125A	
-40 C to 125 C	SSOP - DB	Reel of 2000	SN74LVC125ADBR	LC125A	
		Tube of 90	SN74LVC125APW		
	TSSOP - PW	Reel of 2000	SN74LVC125APWR	LC125A	
		Reel of 250	SN74LVC125APWT		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



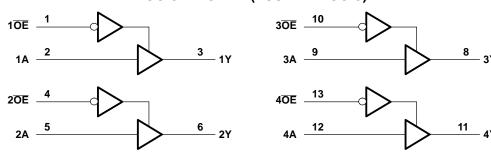
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FUNCTION TABLE (EACH BUFFER)

INP	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	Н
L	L	L
Н	X	Z

LOGIC DIAGRAM (POSITIVE LOGIC)

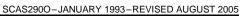


Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Output voltage range ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
		D package ⁽⁴⁾		86	
		DB package ⁽⁴⁾		96	
θ_{JA}	Package thermal impedance	NS package ⁽⁴⁾		76	°C/W
		PW package ⁽⁴⁾		113	
		RGY package ⁽⁵⁾		47	
T _{stg}	Storage temperature range		-65	150	°C
P _{tot}	Power dissipation	$T_A = -40^{\circ}C \text{ to } 125^{\circ}C^{(6)(7)}$		500	mW

- Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings (1) only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- The value of V_{CC} is provided in the recommended operating conditions table.
- The package thermal impedance is calculated in accordance with JESD 51-7.
- The package thermal impedance is calculated in accordance with JESD 51-5.
- For the DB, NS, and PW packages: above 60°C, the value of P_{tot} derates linearly with 8 mW/K.





Recommended Operating Conditions⁽¹⁾

			T _A =	25°C	-40°C	to 85°C	–40°C t	o 125°C	
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
V	Cumply voltage	Operating	1.65 3.6 1.5		1.65	3.6	1.65	3.6	V
V _{CC}	Supply voltage	Data retention only			1.5		1.5		V
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		1.7		1.7		V
	input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2		2		
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$	
V_{IL}	/ _{IL} Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		0.7		0.7		0.7	V
	input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		0.8		0.8	
VI	Input voltage		0	5.5	0	5.5	0	5.5	V
Vo	Output voltage		0	V _{CC}	0	V _{CC}	0	V_{CC}	V
		V _{CC} = 1.65 V		-4		-4		-4	
	High-level	V _{CC} = 2.3 V		-8		-8		-8	A
I _{OH}	output current	V _{CC} = 2.7 V		-12		-12	-12		mA
		V _{CC} = 3 V		-24		-24		-24	
		V _{CC} = 1.65 V		4		4		4	
	Low-level output current	V _{CC} = 2.3 V		8		8		8	A
I _{OL}		V _{CC} = 2.7 V	12			12		12	mA
		V _{CC} = 3 V		24	24		24		
Δt/Δν	Input transition ris	se or fall rate		8		8		8	ns/V

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	T _A	= 25°C		–40°C to	85°C	-40°C to 125°C		LINUT
PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	$I_{OH} = -100 \mu A$	1.65 V to 3.6 V	V _{CC} - 0.2			V _{CC} - 0.2		V _{CC} - 0.3		
	I _{OH} = -4 mA	1.65 V	1.29			1.2		1.05		
V	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			1.7		1.55		V
V _{OH}	1 12 m A	2.7 V	2.2			2.2		2.05		V
	$I_{OH} = -12 \text{ mA}$	3 V	2.4			2.4		2.25		
	I _{OH} = -24 mA	3 V	2.3			2.2		2		
	$I_{OL} = 100 \mu A$	1.65 V to 3.6 V			0.1		0.2		0.3	
	$I_{OL} = 4 \text{ mA}$	1.65 V			0.24		0.45		0.6	
V_{OL}	$I_{OL} = 8 \text{ mA}$	2.3 V			0.3		0.7		0.75	V
	I _{OL} = 12 mA	2.7 V			0.4		0.4		0.6	
	I _{OL} = 24 mA	3 V			0.55		0.55		0.8	
l _l	V _I = 5.5 V or GND	3.6 V			±1		±5		±20	μΑ
I _{OZ}	$V_O = V_{CC}$ or GND	3.6 V			±1		±10		±20	μΑ
I _{cc}	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			1		10		40	μΑ
Δl _{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	2.7 V to 3.6 V			500		500		5000	μА
C _i	V _I = V _{CC} or GND	3.3 V		5						pF

SN74LVC125A QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS





Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	V	T,	_λ = 25°C	;	–40°C to	o 85°C	–40°C to	125°C	UNIT
PARAMETER	(INPUT) (OUTPUT)		V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			1.8 V ± 0.15 V	1	4.5	11.8	1	12.3	1	13.8	
	Α	Υ	2.5 V ± 0.2 V	1	2.7	5.8	1	6.3	1	8.4	no
t _{pd}	A	T	2.7 V	1	3	5.3	1	5.5	1	7	ns
			$3.3~\text{V}\pm0.3~\text{V}$	1	2.5	4.6	1	4.8	1	6	
		Y	1.8 V ± 0.15 V	1	4.3	13.8	1	14.3	1	15.8	ns
	ŌĒ		2.5 V ± 0.2 V	1	2.7	6.9	1	7.4	1	9.5	
t _{en}	OE		2.7 V	1	3.3	6.4	1	6.6	1	8.5	
			3.3 V ± 0.3 V	1	2.4	5.2	1	5.4	1	7	
			1.8 V ± 0.15 V	1	4.3	10.6	1	11.1	1	12.6	
	ŌĒ	Y	2.5 V ± 0.2 V	1	2.2	5.1	1	5.6	1	7.7	
t _{dis}	OE .	Y	2.7 V	1	2.5	4.8	1	5	1	6.5	ns
			3.3 V ± 0.3 V	1	2.4	4.4	1	4.6	1	6	
t _{sk(o)}			3.3 V ± 0.3 V					1		1.5	ns

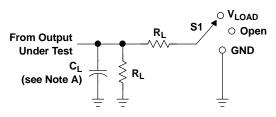
Operating Characteristics

T_A = 25°C

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			1.8 V	7.4	
C _{pd}	Power dissipation capacitance per gate	f = 10 MHz	2.5 V	11.3	pF
			3.3 V	15	



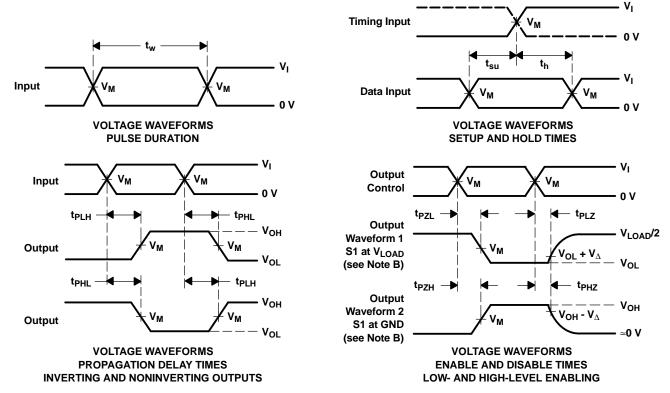
PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

v	INF	PUTS	.,	.,		_	.,
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	$oldsymbol{V}_{\Delta}$
1.8 V ± 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LVC125AD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ADBLE	OBSOLETE	SSOP	DB	14		TBD	Call TI	Call TI
SN74LVC125ADBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ADBRG4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
SN74LVC125ADE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ADR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ADRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ADRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ADT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ADTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ANSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ANSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWLE	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI
SN74LVC125APWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWTE4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125APWTG4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC125ARGYR	ACTIVE	QFN	RGY	14	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
SN74LVC125ARGYRG4	ACTIVE	QFN	RGY	14	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs. **LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.



PACKAGE OPTION ADDENDUM

18-Oct-2006

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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D (R-PDSO-G14)

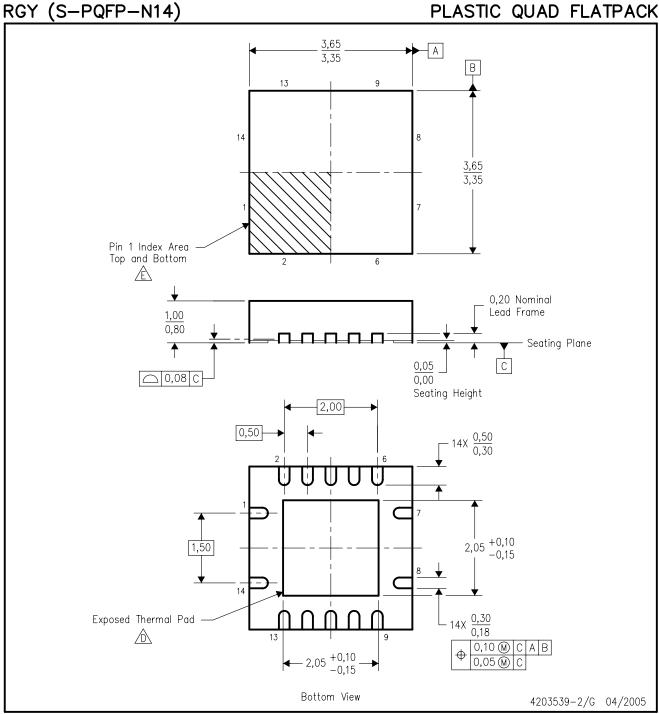
PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BA.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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